NSN 5961-01-516-7501

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-516-7501 **Inclosure Material:** Glass **Overall Length:** Between 53.9 millimeters and 55.3 millimeters **Terminal Length:** 25.4 millimeters **Overall Diameter:** Between 1.5 millimeters and 1.9 millimeters **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-35 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 11.0 regulator voltage **Current Rating Per Characteristic:** 10.00 milliamperes source cutoff current horsepower metric **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No